

## Update of the optical light transport in Geant4 to model optical coating

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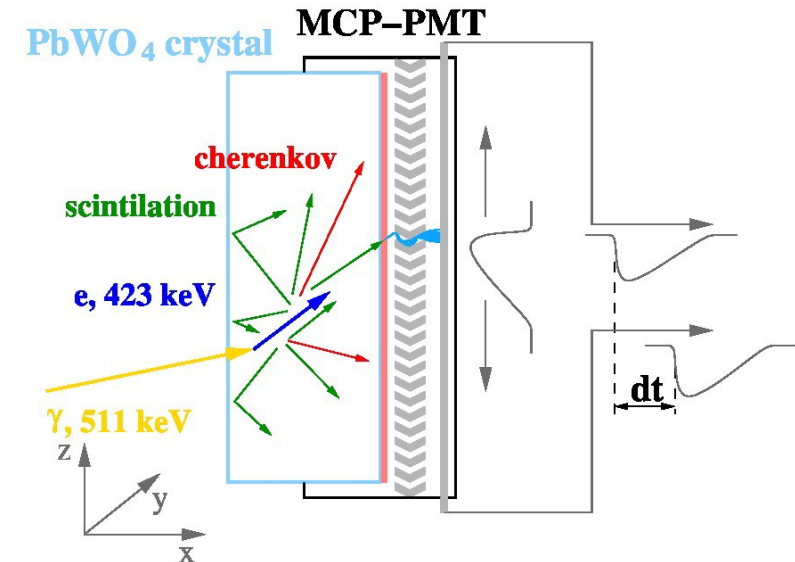
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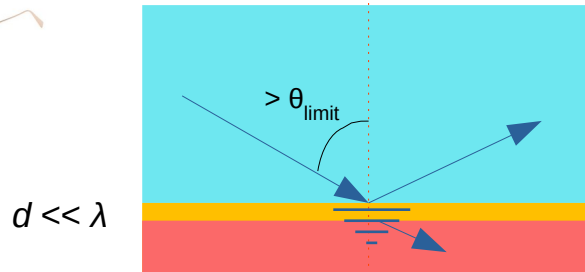
# I. Context: the ClearMind project

# Introduction of the ClearMind project

- Collaboration between CEA-IRFU, IJCLab and CPPM
- New PET detector with improved spatio-temporal resolution
  - **PWO** crystal: Cerenkov (21 photon/event at 511 keV) and scintillation (200 photon/event at 511 keV) production, with fast constants ( $\sim 2$  ns)
  - Deposit the photoelectric layer ( $n_{PC} > n_{PWO}$ ) directly on the crystal: **scintronic crystal** to improve detection efficiency
  - Use **Micro-Channel Plate (MCP-PMT)** for precise timing
  - **Passivation** of PWO/PC interface to protect photocathode from oxidation



# Thin layer introduction



If  $n_1 > n_{TL}$ :

$$\theta_L = \arcsin\left(\frac{n_{TL}}{n_1}\right)$$

## Consequences

- Interference phenomenon at the interfaces
- For  $\theta > \theta_L$  an evanescent wave is produced and allows **frustrated transmission**

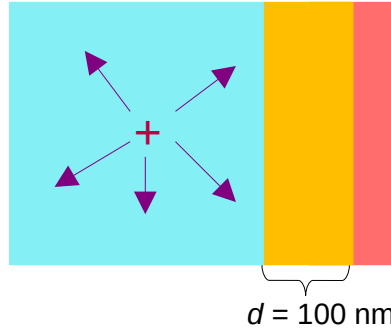


Iridescence phenomenon



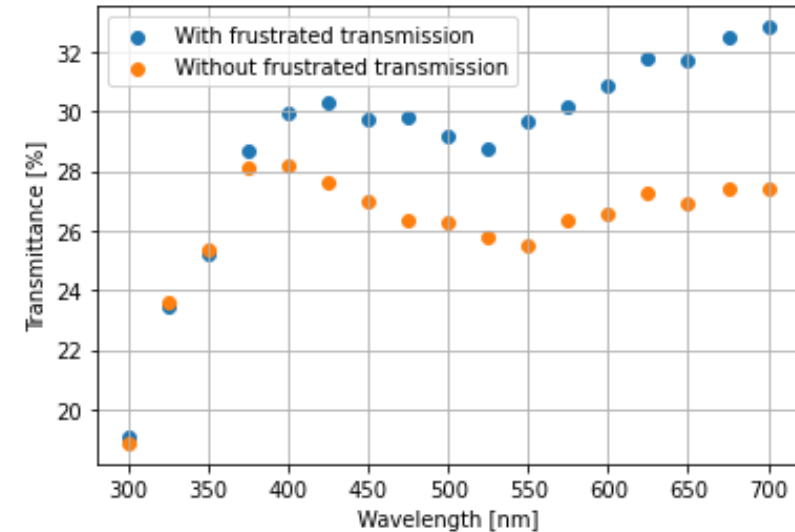
Near field microscopy

# Importance of the frustrated transmission



- Three medium PWO, TL, PC
- TL: thin layer with 100 nm thickness
- Absorption length of the crystal is fixed
- Optical photons generated from the center of the crystal
- Isotropically

Transmittance to photocathode with and without frustrated transmission as a function of wavelength for isotropic photon generation



→ Transmittance increases by 4 % thanks to frustrated transmission

→ Simulation of thin layer phenomena is essential

## II. Implementation in Geant4

# Integration of thin layer in Geant4

- New function in G4OpBoundaryProcess class, based on DielectricDielectric()

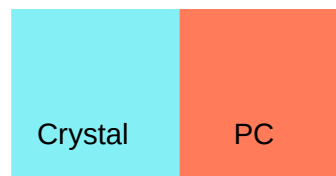
```
void DielectricMetal();
void DielectricDielectric();
void DielectricLUT();
void DielectricLUTDAVIS();
void DielectricDichroic();
void CoatedDielectricDielectric();
```

- New Surface Type:

```
enum G4SurfaceType
{
    dielectric_metal,
    dielectric_dielectric,
    coated,
    dielectric_LUT,
    dielectric_LUTDAVIS,
    dielectric_dichroic,
    firsov,
    x_ray
};
```

- New Status:

```
enum G4OpBoundaryProcessStatus
{
    Undefined,
    Transmission,
    FresnelRefraction,
    FresnelReflection,
    TotalInternalReflection,
    LambertianReflection,
    .
    .
    .
    Dichroic,
    CoatedDielectricReflection,
    CoatedDielectricRefraction,
    CoatedDielectricFrustratedTransmission
};
```



- thickness ? → ThicknessTL
- refractive index ? → RindexTL
- frustrated ?



# III. Theoretical transmittance through the thin layer

# Formulas of reflection and transmission

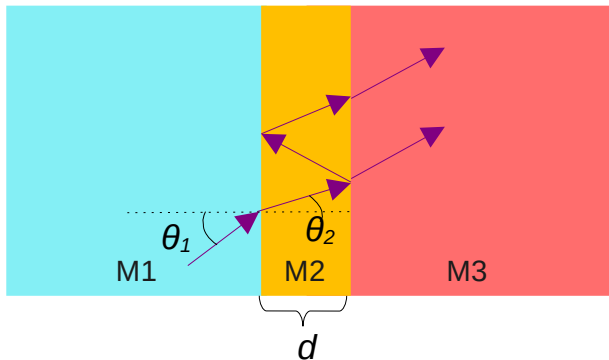
M1

M2

**Fresnel coefficient** (used by DielectricDielectric())

		Reflection	Transmission
Normal incidence		$r_{ij,TE} = r_{ij,TM} = \frac{n_i - n_j}{n_i + n_j}$	$t_{ij,TE} = t_{ij,TM} = \frac{2 n_i}{n_i + n_j}$
Oblique incidence	$\theta_i < \theta_j$	$r_{ij,TE} = \frac{n_i \cos \theta_i - n_j \cos \theta_j}{n_i \cos \theta_i + n_j \cos \theta_j}$ $r_{ij,TM} = \frac{n_i \cos \theta_j - n_j \cos \theta_i}{n_i \cos \theta_j + n_j \cos \theta_i}$	$t_{ij,TE} = \frac{2 n_i \cos \theta_i}{n_i \cos \theta_i + n_j \cos \theta_j}$ $t_{ij,TM} = \frac{2 n_i \cos \theta_i}{n_i \cos \theta_j + n_j \cos \theta_i}$
	$\theta_i > \theta_j$	Total internal reflection	

# Formulas of reflection and transmission



## Coefficient of transmission and reflection through thin layer

(used by CoatedDielectricDielectric())

$$t = \frac{t_{12} t_{23} e^{i\beta}}{1 + r_{12} r_{23} e^{2i\beta}}$$

$$r = \frac{r_{12} + r_{23} \cdot e^{2i\beta}}{1 + r_{12} \cdot r_{23} \cdot e^{2i\beta}}$$

Not possible in Geant4 yet

$\theta_1 < \theta_L :$

$\theta_2$  existed

$$\beta = k_2 d \cos(\theta_2)$$

$\theta_1 \geq \theta_L :$

$\theta_2$  doesn't exist  
→ replacing  $n_2 \cos \theta_2$  by  $i\gamma$   
in Fresnel coefficient

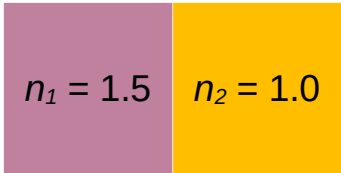
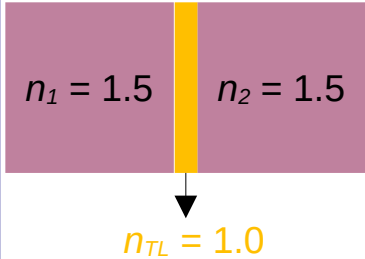
$$\gamma = \sqrt{n_1^2 \sin^2(\theta_1) - n_2^2}$$

$$\beta = i k_0 d \gamma$$

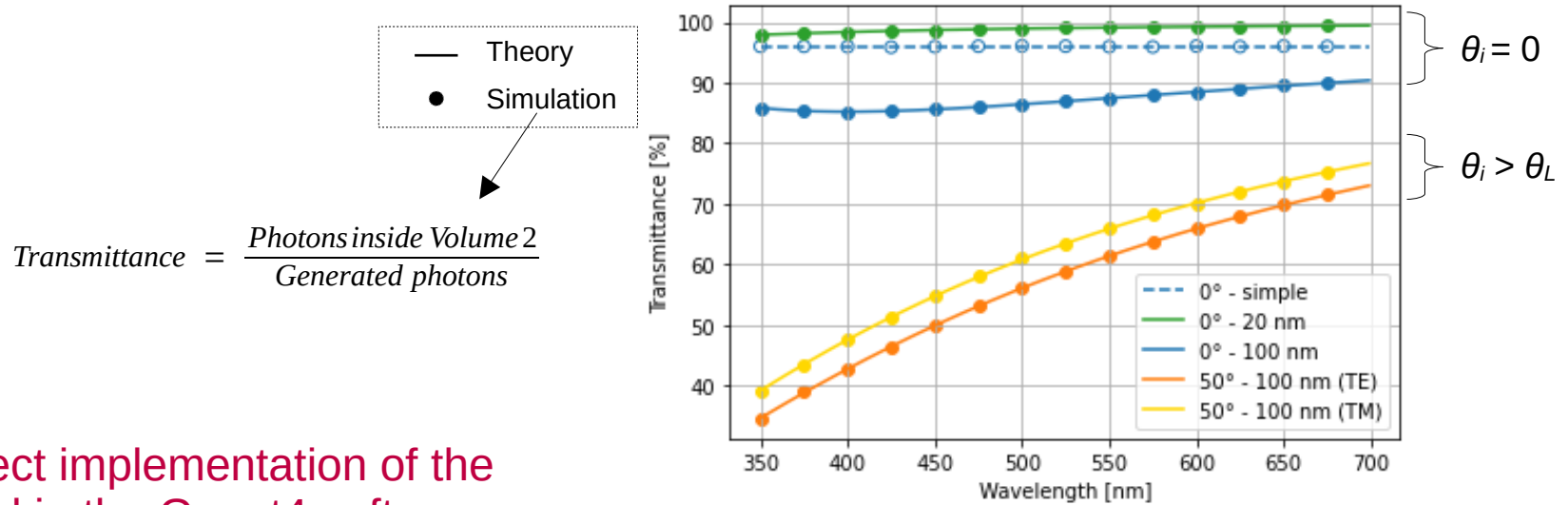
$$k_2 = n_2 \frac{2\pi}{\lambda} = k_0 n_2$$

## IV. Comparison between theoretical and simulated transmittances

# Correctness of the implementation

	What we want to simulate	What we code in Geant4
Simple interface		<p>Physical and Logical Volume: 1 and 2</p> <p>Optical Surface Types: <i>dielectric_dielectric</i></p> <p>Optical photons generated inside M1</p>
Interface composed with thin layer		<p>Physical and Logical Volume: 1 and 2</p> <p>Optical Surface Types: <i>coated</i></p> <p>→ Thickness and Refractive Index of TL</p> <p>Optical photons generated inside M1</p>

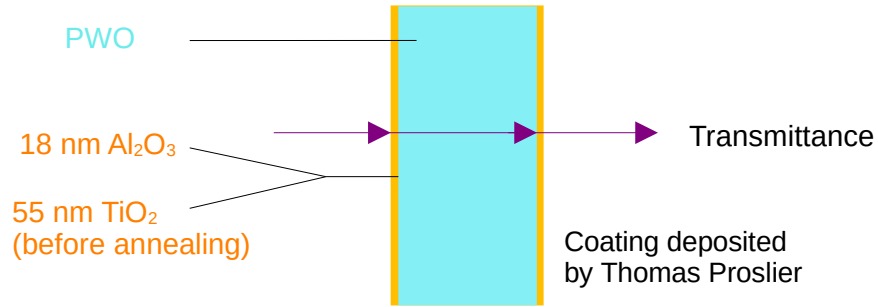
# Correctness of the implementation



Correct implementation of the model in the Geant4 software

# V. Experimental validation of the implemented model

# Experimental validation

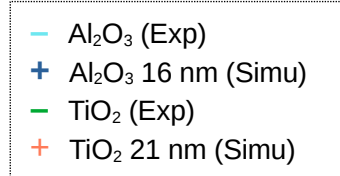


## Hypothesis:

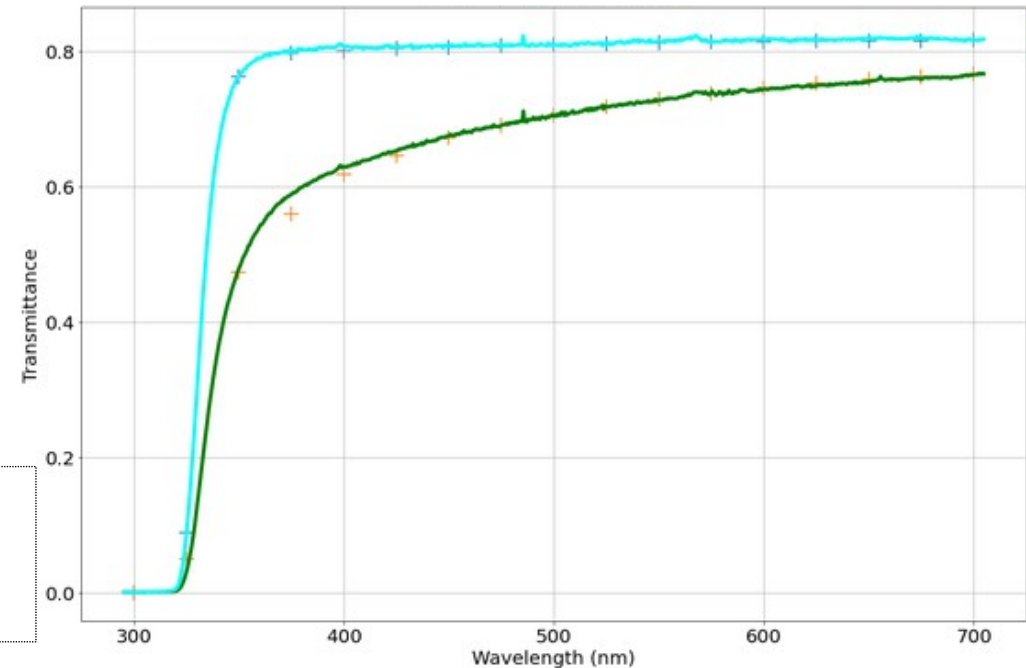
- Refractive index of  $\text{Al}_2\text{O}_3$  and  $\text{TiO}_2$  are known

## Unknown variables:

- Thickness of passivation layer
- Refractive index of PWO
- Attenuation length of PWO



Transmittance as function of wavelength, through a window optically coated on both its faces, depending of the thin layer materials





# Conclusion

- Simulation of transmittance through thin layer with Geant4 is essential to model the ClearMind detector
- Perfect agreement between simulated and theoretical transmittance
- The model has also been validated experimentally
- This update may be of interest for any modeling of light transport including optical coating in G4